

ESD and Surge Protection Device

Low Clamping Voltage Surge Protection Diode Array

NSP4201MR6

The NSP4201MR6 surge protector is designed to protect high speed data lines from ESD, EFT, and lightning surges.

Features

- Protection for the Following IEC Standards:
IEC 61000-4-2 (ESD) ± 30 kV (Contact)
IEC 61000-4-5 (Lightning) 25 A (8/20 μ s)
- Low Clamping Voltage
- Low Leakage
- UL Flammability Rating of 94 V-0
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- High Speed Communication Line Protection
- USB 1.1 and 2.0 Power and Data Line Protection
- Digital Video Interface (DVI)
- Monitors and Flat Panel Displays

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Power Dissipation 8/20 μ s @ T _A = 25°C (Note 1)	P _{pk}	500	W
Operating Junction Temperature Range	T _J	-40 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C
Lead Solder Temperature - Maximum (10 Seconds)	T _L	260	°C
IEC 61000-4-2 Air (ESD) IEC 61000-4-2 Contact (ESD)	ESD	± 30	kV
IEC 61000-4-4 (5/50 ns)	EFT	40	A

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

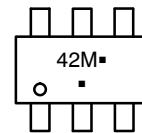
1. Non-repetitive current pulse per Figure 1 (Pin 5 to Pin 2)

See Application Note [AND8308/D](#) for further description of survivability specs.



TSOP-6
CASE 318G

MARKING DIAGRAM



42 = Specific Device Code

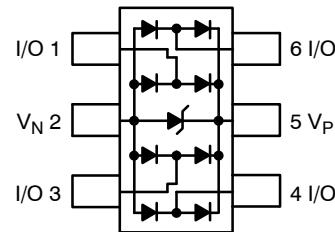
M = Date Code

▪ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary
depending upon manufacturing location.

PIN CONFIGURATION AND SCHEMATIC



ORDERING INFORMATION

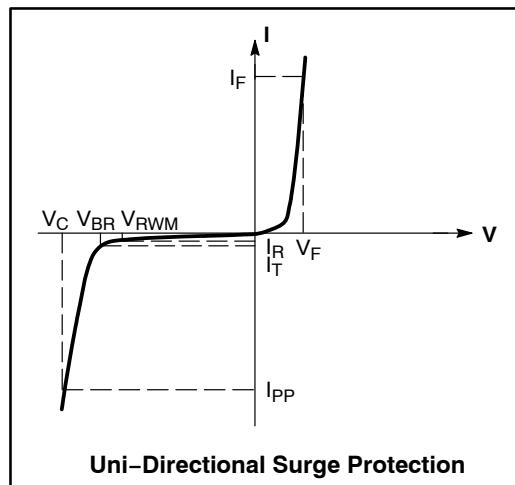
Device	Package	Shipping
NSP4201MR6T1G	TSOP-6 (Pb-Free)	3000 / Tape & Reel
SZNSP4201MR6T1G	TSOP-6 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, [BRD8011/D](#).

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
I _T	Test Current
I _F	Forward Current
V _F	Forward Voltage @ I _F
P _{pk}	Peak Power Dissipation
C	Capacitance @ V _R = 0 and f = 1.0 MHz



*See Application Note [AND8308/D](#) for detailed explanations of datasheet parameters.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			5.0	V
Breakdown Voltage	V _{BR}	I _T = 1 mA, (Note 3)	6.0			V
Reverse Leakage Current	I _R	V _{RWM} = 5 V			1.0	µA
Clamping Voltage (t _p = 8/20 µs per Figure 1)	V _C	I _{PP} = 1 A, Any I/O to GND			9.0	V
		I _{PP} = 5 A, Any I/O to GND			10.5	
		I _{PP} = 8 A, Any I/O to GND			11.5	
		I _{PP} = 25 A, Any I/O to GND			14.0	
Junction Capacitance	C _J	V _R = 0 V, f = 1 MHz between I/O Pins and GND		3.0	5.0	pF
Junction Capacitance	C _J	V _R = 0 V, f = 1 MHz between I/O Pins		1.5	3.0	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Surge protection devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.
3. V_{BR} is measured at pulse test current I_T.

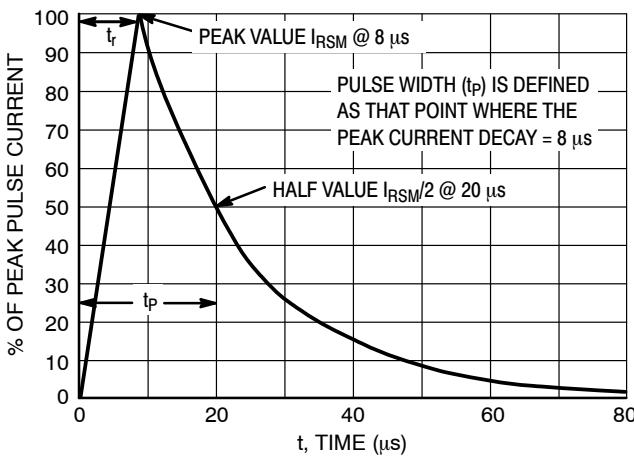
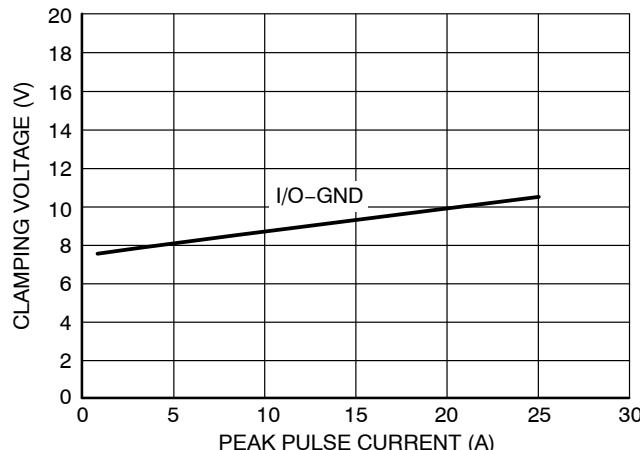


Figure 1. IEC61000-4-5 8/20 µs Pulse Waveform

Figure 2. Clamping Voltage vs. Peak Pulse Current
(t_p = 8/20 µs per Figure 1)

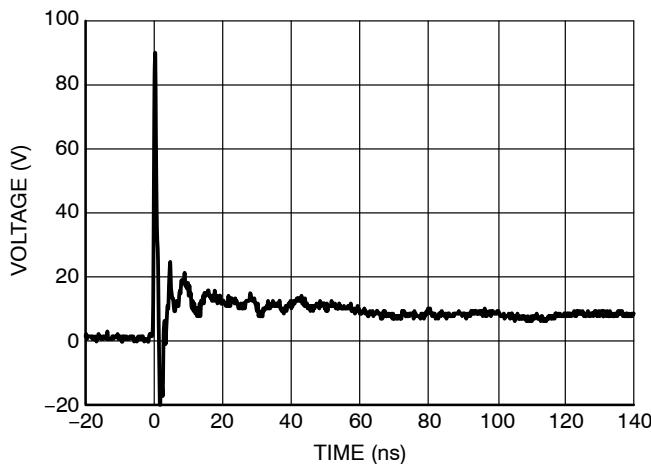


Figure 3. IEC61000-4-2 +8 kV Contact Clamping Voltage

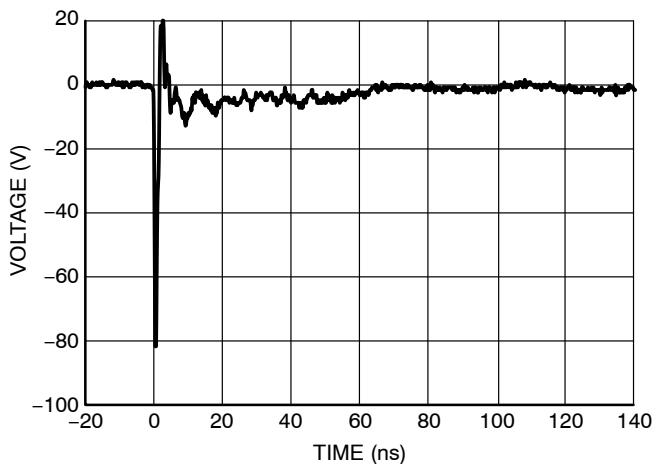


Figure 4. IEC61000-4-2 -8 kV Contact Clamping Voltage

IEC 61000-4-2 Spec.

Level	Test Voltage (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

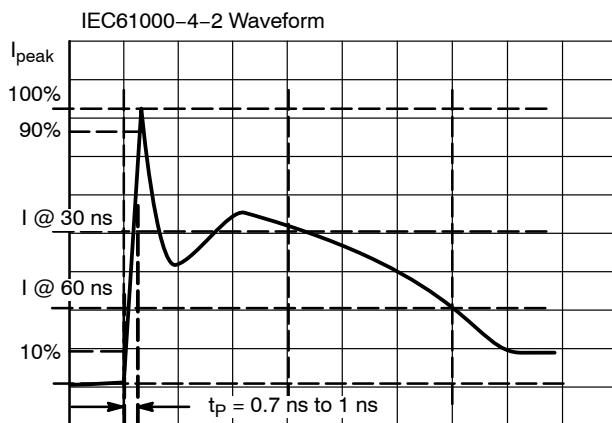


Figure 5. IEC61000-4-2 Spec

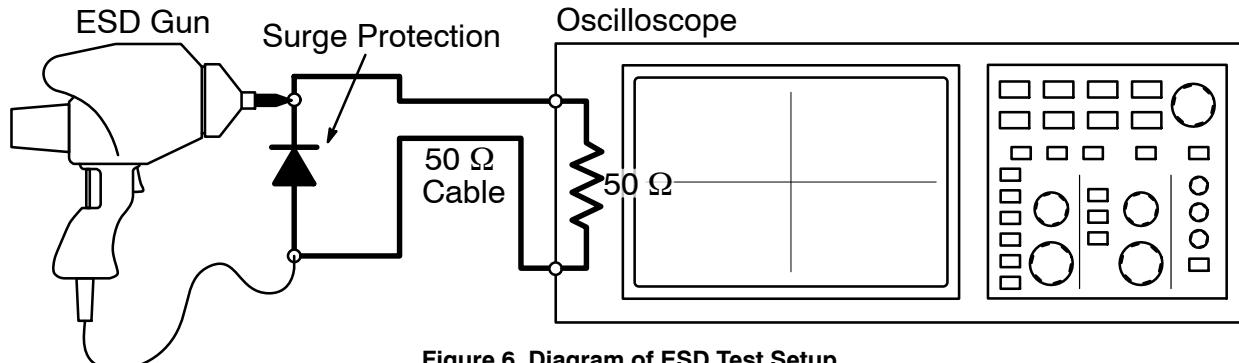


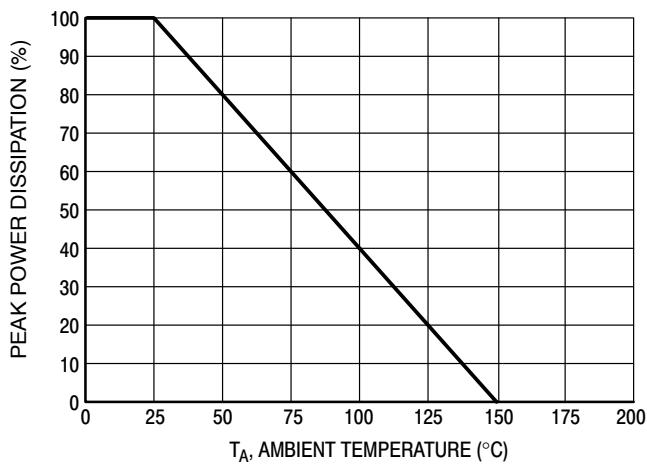
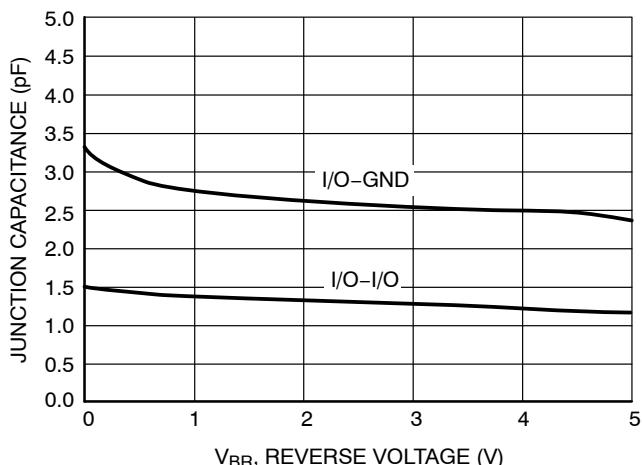
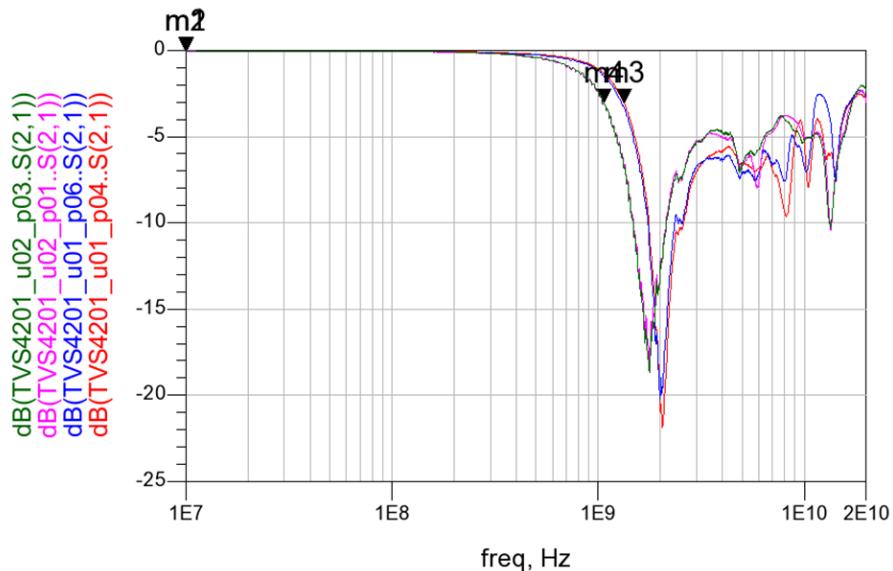
Figure 6. Diagram of ESD Test Setup

The following is taken from Application Note [AND8308/D](#) – Interpretation of Datasheet Parameters for ESD Devices.

ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger

systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. **onsemi** has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how **onsemi** creates these screenshots and how to interpret them please refer to [AND8307/D](#).

TYPICAL PERFORMANCE CURVES $(T_J = 25^\circ\text{C} \text{ unless otherwise noted})$ **Figure 7. Pulse Derating Curve****Figure 8. Junction Capacitance vs Reverse Voltage****Figure 9. RF Insertion Loss**

TYPICAL APPLICATIONS

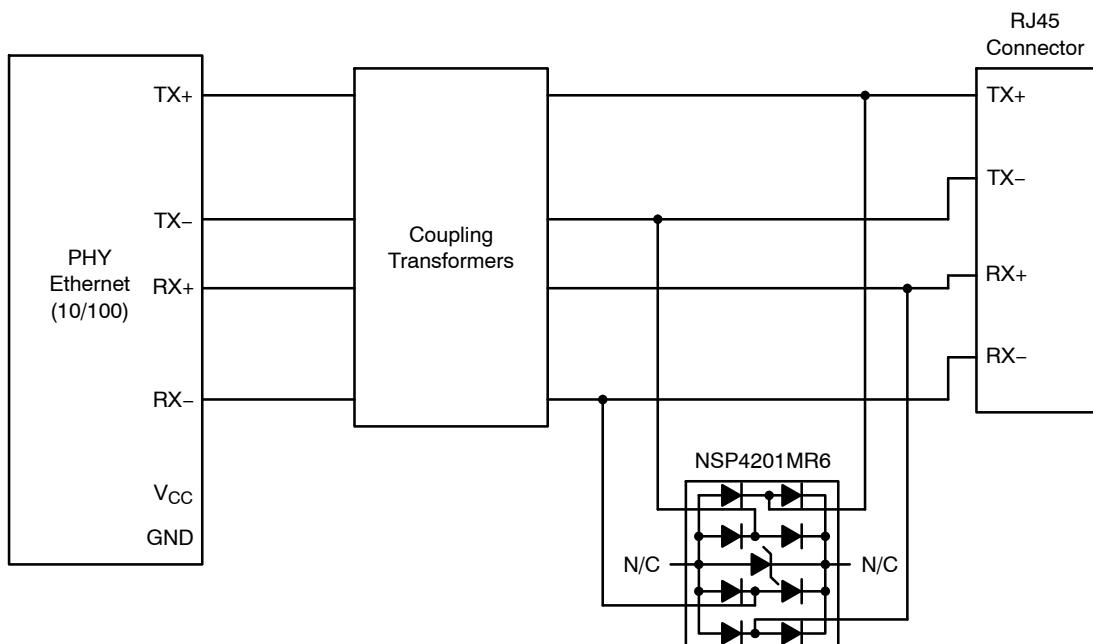


Figure 10. Protection for Ethernet 10/100 (Differential mode)

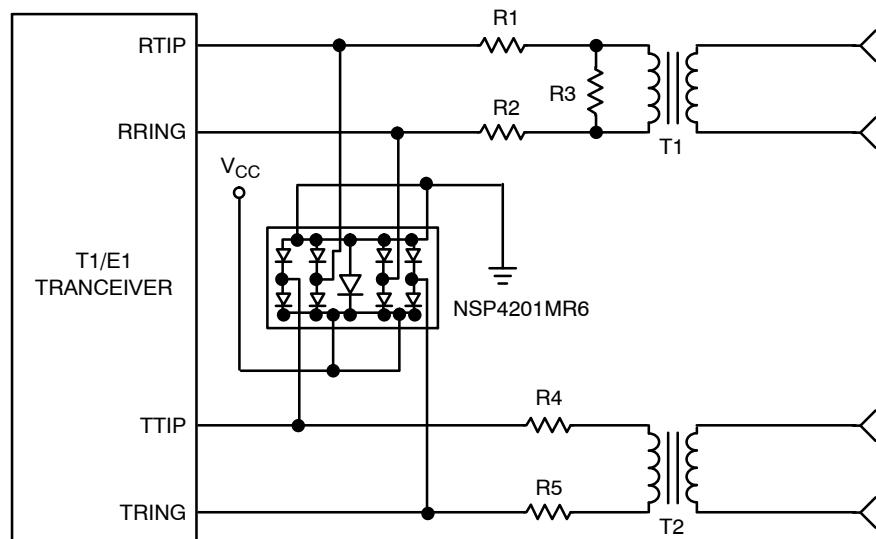
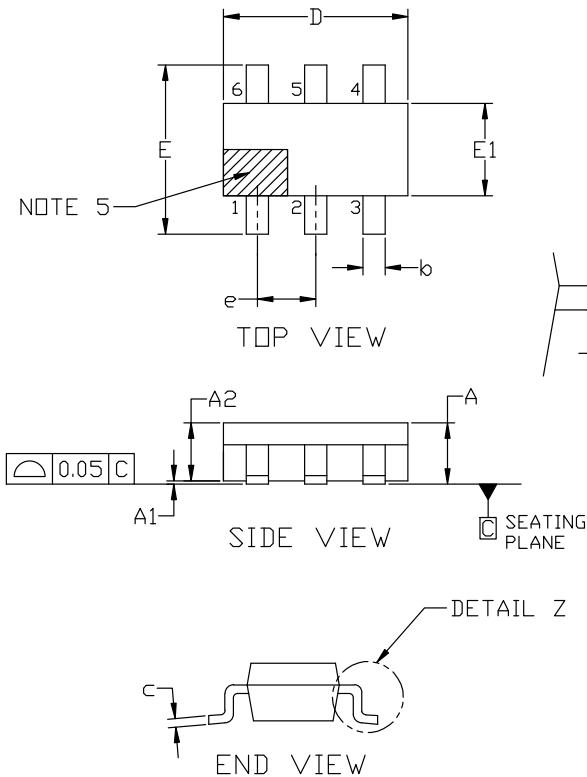


Figure 11. TI/E1 Interface Protection

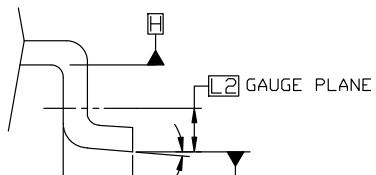

TSOP-6 3.00x1.50x0.90, 0.95P
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ISSUE W

DATE 26 FEB 2024

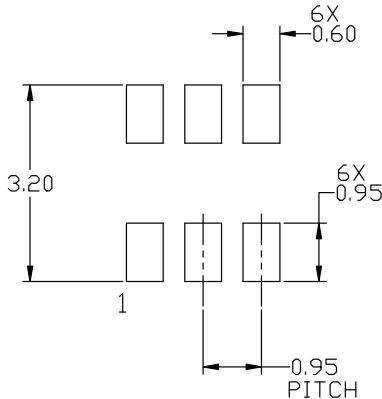


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
5. PIN 1 INDICATOR MUST BE LOCATED IN THE INDICATED ZONE



MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.90	1.00	1.10
A1	0.01	0.06	0.10
A2	0.80	0.90	1.00
b	0.25	0.38	0.50
c	0.10	0.18	0.26
D	2.90	3.00	3.10
E	2.50	2.75	3.00
E1	1.30	1.50	1.70
e	0.85	0.95	1.05
L	0.20	0.40	0.60
L2	0.25 BSC		
M	0°	---	10°



RECOMMENDED MOUNTING FOOTPRINT

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference manual, SOLDERMM/D.

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CASE 318G

ISSUE W

DATE 26 FEB 2024

**GENERIC
MARKING DIAGRAM***

IC

XXX = Specific Device Code
 A = Assembly Location
 Y = Year
 W = Work Week
 ▪ = Pb-Free Package

STANDARD

XXX = Specific Device Code
 M = Date Code
 ▪ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:
 PIN 1. DRAIN
 2. DRAIN
 3. GATE
 4. SOURCE
 5. DRAIN
 6. DRAIN

STYLE 2:
 PIN 1. Emitter 2
 2. Base 1
 3. Collector 1
 4. Emitter 1
 5. Base 2
 6. Collector 2

STYLE 3:
 PIN 1. ENABLE
 2. N/C
 3. R BOOST
 4. Vz
 5. Vin
 6. Vout

STYLE 4:
 PIN 1. N/C
 2. Vin
 3. NOT USED
 4. GROUND
 5. ENABLE
 6. LOAD

STYLE 5:
 PIN 1. Emitter 2
 2. Base 2
 3. Collector 1
 4. Emitter 1
 5. Base 1
 6. Collector 2

STYLE 6:
 PIN 1. COLLECTOR
 2. COLLECTOR
 3. BASE
 4. Emitter
 5. COLLECTOR
 6. COLLECTOR

STYLE 7:
 PIN 1. COLLECTOR
 2. COLLECTOR
 3. BASE
 4. N/C
 5. COLLECTOR
 6. Emitter

STYLE 8:
 PIN 1. Vbus
 2. D(in)
 3. D(in)+
 4. D(out)+
 5. D(out)
 6. GND

STYLE 9:
 PIN 1. LOW VOLTAGE GATE
 2. DRAIN
 3. SOURCE
 4. DRAIN
 5. DRAIN
 6. HIGH VOLTAGE GATE

STYLE 10:
 PIN 1. D(OUT)+
 2. GND
 3. D(OUT)-
 4. D(IN)-
 5. VBUS
 6. D(IN)+

STYLE 11:
 PIN 1. SOURCE 1
 2. DRAIN 2
 3. DRAIN 2
 4. SOURCE 2
 5. GATE 1
 6. DRAIN 1/GATE 2

STYLE 12:
 PIN 1. I/O
 2. GROUND
 3. I/O
 4. I/O
 5. VCC
 6. I/O

STYLE 13:
 PIN 1. GATE 1
 2. SOURCE 2
 3. GATE 2
 4. DRAIN 2
 5. SOURCE 1
 6. DRAIN 1

STYLE 14:
 PIN 1. ANODE
 2. SOURCE
 3. GATE
 4. CATHODE/DRAIN
 5. CATHODE/DRAIN
 6. CATHODE/DRAIN

STYLE 15:
 PIN 1. ANODE
 2. SOURCE
 3. GATE
 4. DRAIN
 5. N/C
 6. CATHODE

STYLE 16:
 PIN 1. ANODE/CATHODE
 2. BASE
 3. Emitter
 4. COLLECTOR
 5. ANODE
 6. CATHODE

STYLE 17:
 PIN 1. Emitter
 2. BASE
 3. ANODE/CATHODE
 4. ANODE
 5. CATHODE
 6. COLLECTOR

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